**FAIRCHILD** SEMICONDUCTOR

## 30V N-Channel PowerTrench<sup>o</sup> MOSFET

### **General Description**

This N-Channel MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for "low side" synchronous rectifier operation, providing an extremely low  $R_{DS(ON)}$  in a small package.

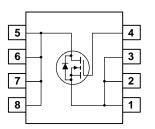
## Applications

• DC/DC converter

## Features

- 14 A, 30 V.  $R_{DS(ON)} = 7.5 \ m\Omega \ @ V_{GS} = 10 \ V$  $R_{DS(ON)} = 9.0 \ m\Omega \ @ V_{GS} = 4.5 \ V$
- Low gate charge (22 nC typical)
- High performance trench technology for extremely low  $R_{\text{DS}(\text{ON})}$
- High power and current handling capability



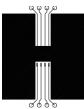


## Absolute Maximum Ratings T<sub>A=25°C</sub> unless otherwise noted

Symbol	Parameter			Ratings	Units
V <sub>DSS</sub>	Drain-Source Voltage			30	
V <sub>GSS</sub>	Gate-Source Voltage			±20	
I <sub>D</sub>	Drain Curre	nt – Continuous	(Note 1a)	14	A
		– Pulsed		50	
P <sub>D</sub>	Power Dissipation for Single Operation		(Note 1a)	2.5	W
			(Note 1b)	1.2	
			(Note 1c)	1.0	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range		rature Range	-55 to +150	°C
Therma	I Charact	eristics			
R <sub>eJA</sub>	Thermal Resistance, Junction-to-Ambient (Note 1a)		nt (Note 1a)	50	
R <sub>θJC</sub>	Thermal Resistance, Junction-to-Case (Note 1)			25	
Packag	e Marking	g and Ordering In	formation		·
Device Marking		Device	Reel Size	Tape width	Quantity
FDS6682		FDS6682	13"	12mm	2500 units

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Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics	<u> </u>				
BV <sub>DSS</sub>	Drain–Source Breakdown Voltage	$V_{GS} = 0 V$ , $I_D = 250 \mu A$	30			V
<u>ΔBV<sub>DSS</sub></u> ΔT <sub>J</sub>	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$ , Referenced to $25^{\circ}\text{C}$		23		mV/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS} = 24 \text{ V}, \qquad V_{GS} = 0 \text{ V}$			10	μA
I <sub>GSSF</sub>	Gate–Body Leakage, Forward	$V_{GS} = 20 \text{ V}, \qquad V_{DS} = 0 \text{ V}$			100	nA
I <sub>GSSR</sub>	Gate–Body Leakage, Reverse	$V_{GS} = -20 \text{ V},  V_{DS} = 0 \text{ V}$			-100	nA
On Char	acteristics (Note 2)					
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}$ , $I_D = 250 \ \mu A$	1	1.7	3	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D$ = 250 µA, Referenced to 25°C		-5.6		mV/°C
R <sub>DS(on)</sub>	Static Drain–Source On–Resistance	$ \begin{array}{ll} V_{GS} = 10 \text{ V}, & I_D = 14 \text{ A} \\ V_{GS} = 4.5 \text{ V}, & I_D = 12.5 \text{ A} \\ V_{GS} = 4.5 \text{ V}, & I_D = 12.5 \text{ A}, \text{ T}_{J} = 125^{\circ}\text{C} \end{array} $		5.7 6.6 8	7.5 9 11.5	mΩ
I <sub>D(on)</sub>	On–State Drain Current		50			Α
<b>g</b> fs	Forward Transconductance	$V_{DS} = 10 V$ , $I_D = 14 A$		70		S
Dvnamio	c Characteristics					
Ciss	Input Capacitance	$V_{DS} = 15 V$ , $V_{GS} = 0 V$ ,		2310		pF
Coss	Output Capacitance	f = 1.0 MHz		582		pF
C <sub>rss</sub>	Reverse Transfer Capacitance	-		237		pF
Switchir	g Characteristics (Note 2)	•	•	•	•	
t <sub>d(on)</sub>	Turn–On Delay Time	$V_{DD} = 15 V$ , $I_D = 1 A$ ,		10	20	ns
t <sub>r</sub>	Turn–On Rise Time	$V_{GS} = 10 \text{ V}, \qquad R_{GEN} = 6 \Omega$		7	14	ns
t <sub>d(off)</sub>	Turn–Off Delay Time	-		44	70	ns
t <sub>f</sub>	Turn–Off Fall Time	-		16	29	ns
Qg	Total Gate Charge	$V_{DS} = 15 V$ , $I_D = 14 A$ ,		22	31	nC
Q <sub>gs</sub>	Gate–Source Charge	$V_{GS} = 5 V$		6.4		nC
Q <sub>gd</sub>	Gate–Drain Charge	]		8		nC
Drain-S	ource Diode Characteristics	and Maximum Ratings				
ls	Maximum Continuous Drain–Source				2.1	Α
V <sub>SD</sub>	Drain–Source Diode Forward Voltage	$V_{GS} = 0 V$ , $I_{S} = 2.1 A$ (Note 2)		0.7	1.2	V



a) 50°C/W when mounted on a 1in<sup>2</sup> pad of 2 oz copper

b) 105°C/W when mounted on a .04 in<sup>2</sup> pad of 2 oz copper

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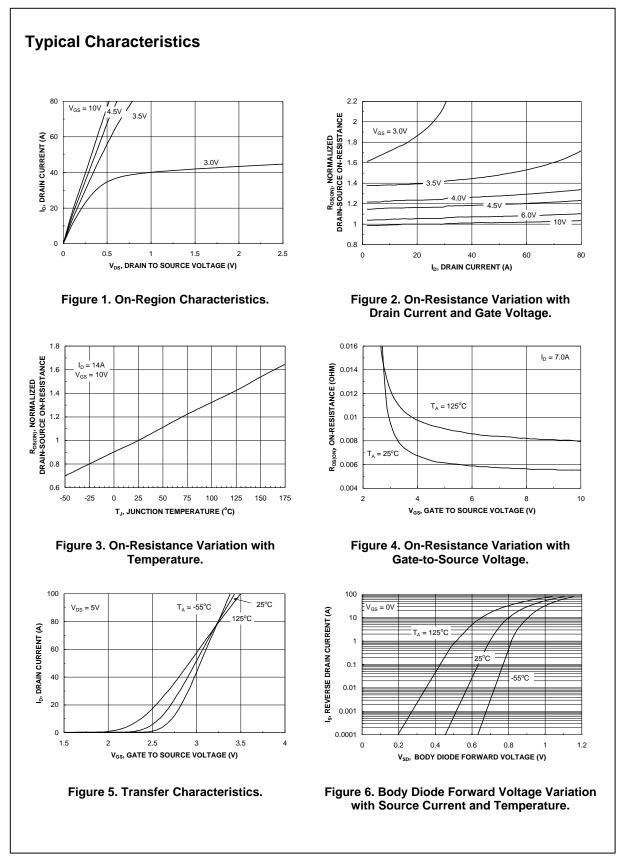
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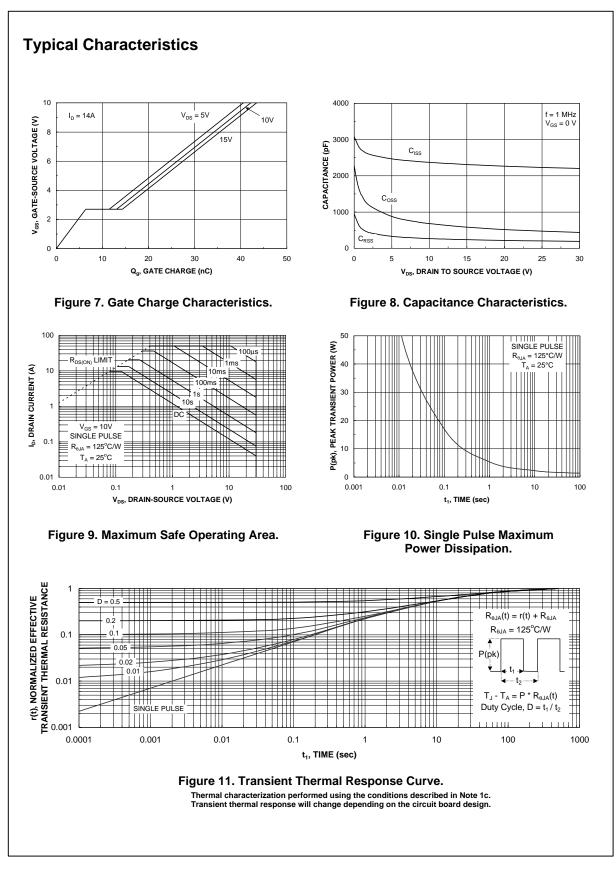
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c) 125°C/W when mounted on a minimum pad.

Scale 1 : 1 on letter size paper

2. Pulse Test: Pulse Width < 300 $\mu$ s, Duty Cycle < 2.0%





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**Definition of Terms** 

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|--------------------------|---------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
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